RENESAS BCR12CS-12LB

Triac

Medium Power Use

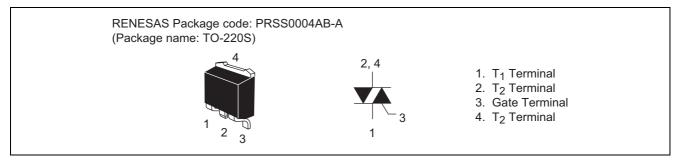
(The product guaranteed maximum junction temperature of 150°C)

REJ03G0470-0300 Rev.3.00 Nov 30, 2007

Features

- I_{T (RMS)} : 12 A
- V_{DRM} : 600 V
- I_{FGTI} , I_{RGTI} , $I_{RGT III}$: 30 mA (20 mA)^{Note6}

Outline



Non-Insulated Type

Planar Passivation Type

Applications

Contactless AC switch, light dimmer, electronic flasher unit, control of household equipment such as TV sets, stereo systems, refrigerator, washing machine, infrared kotatsu, carpet, electric fan, solenoid driver, small motor control, solid state relay, copying machine, electric tool, electric heater control, and other general purpose control applications

Warning

- 1. Refer to the recommended circuit values around the triac before using.
- 2. Be sure to exchange the specification before using. Otherwise, general triacs with the maximum junction temperature of 125°C will be supplied.

Maximum Ratings

Parameter	Symbol	Voltage class	Unit	
	-	12		
Repetitive peak off-state voltage ^{Note1}	V _{DRM}	600	V	
Non-repetitive peak off-state voltage ^{Note1}	V _{DSM}	720	V	

BCR12CS-12LB (The product guaranteed maximum junction temperature of 150°C)

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	12	A	Commercial frequency, sine full wave 360° conduction, Tc = $123^{\circ}C^{Note3}$
Surge on-state current	I _{TSM}	120	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
l ² t for fusing	l ² t	60	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	5	W	
Average gate power dissipation	P _{G (AV)}	0.5	W	
Peak gate voltage	V _{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	—	1.2	g	Typical value

Notes: 1. Gate open.

Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state current		I _{DRM}	—	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	—	_	1.6	V	$Tc = 25^{\circ}C$, $I_{TM} = 20$ A, Instantaneous measurement
Gate trigger voltage ^{Note2}	Ι	V_{FGTI}	—	_	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	V _{RGTI}	—	_	1.5	V	$R_{G} = 330 \Omega$
	III	V _{RGTIII}	—	_	1.5	V	
Gate trigger current ^{Note2}	Ι	I _{FGTI}	_		30 ^{Note6}	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	I _{RGTI}	—	_	30 ^{Note6}	mA	$R_G = 330 \Omega$
	III	I _{RGTIII}	—	_	30 ^{Note6}	mA	
Gate non-trigger voltage		V_{GD}	0.2/0.1	_	_	V	$Tj = 125^{\circ}C/150^{\circ}C, V_{D} = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}	—	_	1.8	°C/W	Junction to case ^{Note3 Note4}
Critical-rate of rise of off-state commutating voltage ^{Note5}		(dv/dt)c	10/1	_	—	V/µs	Tj = 125°C/150°C

Notes: 2. Measurement using the gate trigger characteristics measurement circuit.

3. Case temperature is measured on the T_2 tab.

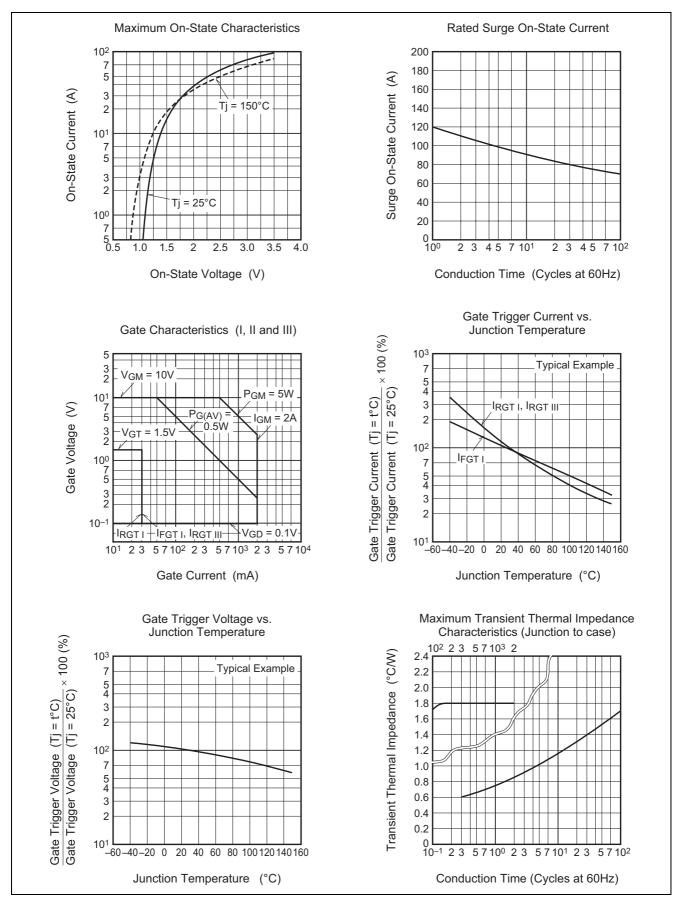
4. The contact thermal resistance $R_{th\,(c\text{-}f)}$ in case of greasing is 1.0°C/W.

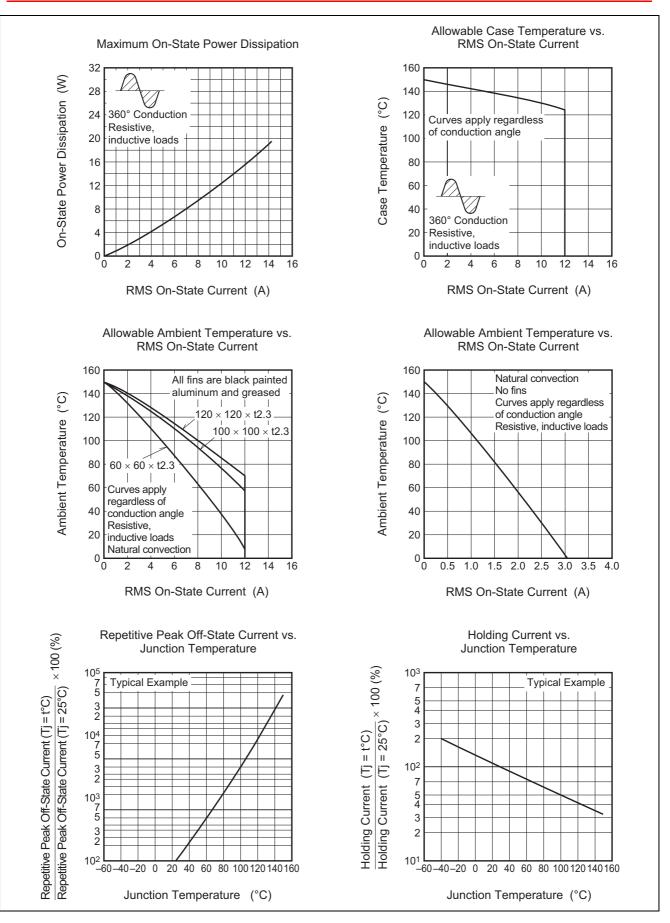
5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

6. High sensitivity (I_{GT} ≤ 20 mA) is also available. (I_{GT} item: 1)

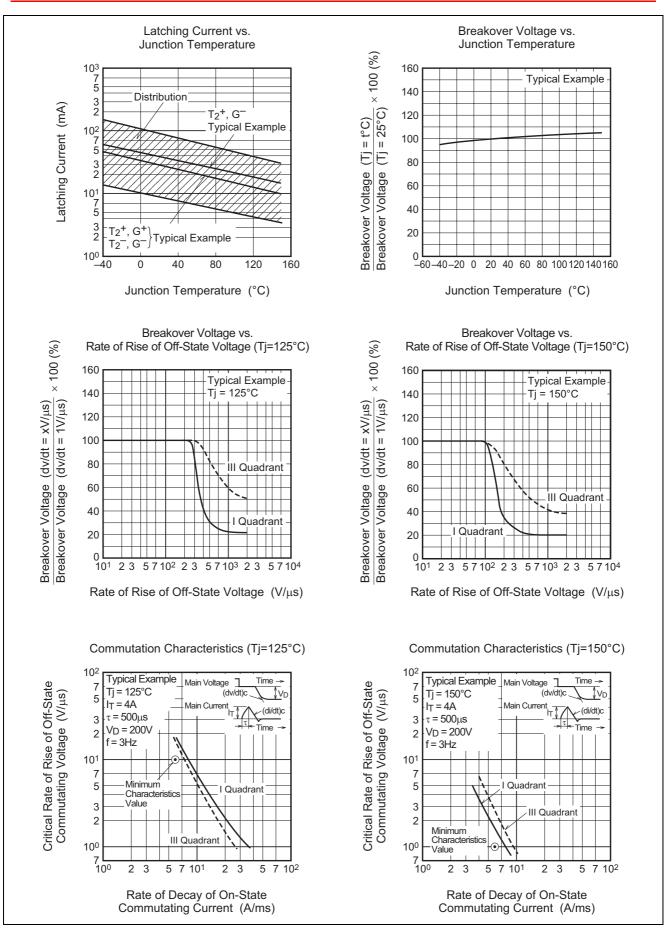
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125°C/150°C	Supply Voltage → Time
2. Rate of decay of on-state commutating current (di/dt)c = - 6.0 A/ms	Main Current → Time
3. Peak off-state voltage $V_D = 400 \text{ V}$	Main Voltage → Time (dv/df)c V _D

Performance Curves

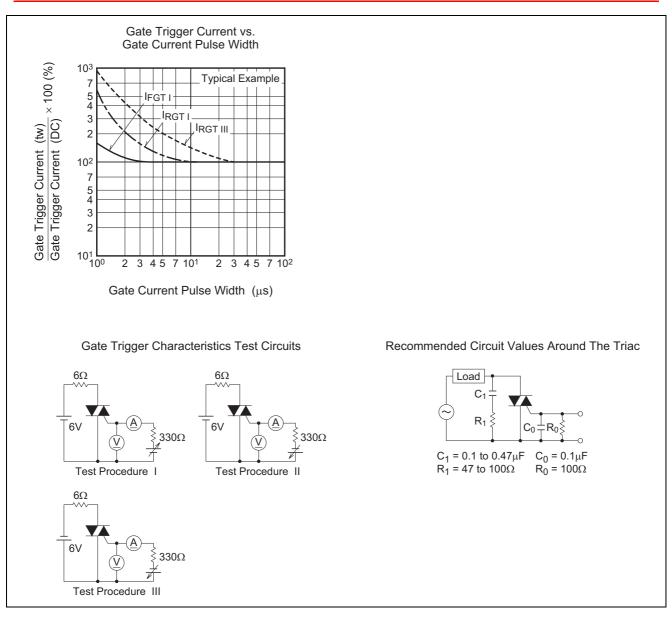




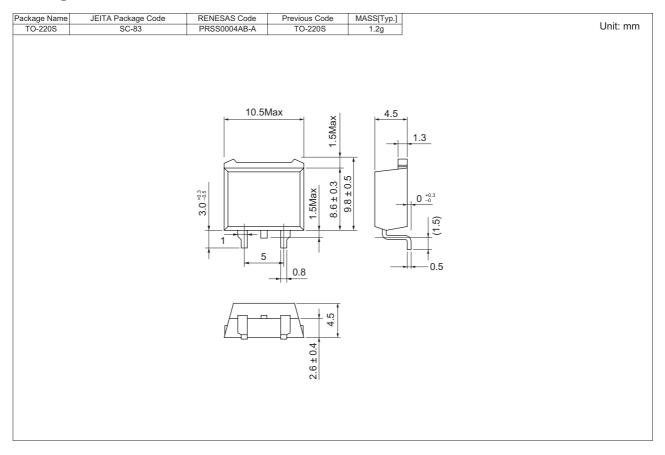
BCR12CS-12LB (The product guaranteed maximum junction temperature of 150°C)



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Package Dimensions



Order Code

Lead form	Standard packing	Quantity	Standard order code	Standard order code example
Surface-mounted type	Taping	1000	Type name – T +Direction (1 or 2) +1	BCR12CS-12LB-T11
Surface-mounted type	Plastic Magazine (Tube)	50	Type name	BCR12CS-12LB

Note : Please confirm the specification about the shipping in detail.

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